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Hyperfast Rectifier, 30 A FRED Pt[®] G5



PRIMARY CHARACTERISTICS						
I _{F(AV)} 30 A						
V _R	1200 V					
V _F at I _F at 125 °C	2.1 V					
t _{rr}	26 ns					
T _J max.	175 °C					
Package	TO-247AD 2L					
Circuit configuration	Single					

FEATURES

- Hyperfast and optimized Q_{rr}
- Best in class forward voltage drop and switching losses trade off
- Optimized for high speed operation
- Optimized for high speed operation
 175 °C maximum operating junction temperature
- Polyimide passivation
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION / APPLICATIONS

Featuring a unique combination of low conduction and switching losses, this rectifier is the right choice for high frequency converters, both soft switched / resonant.

Specifically designed to improve efficiency of PFC and output rectification stages of EV / HEV battery charging stations, booster stage of solar inverters and UPS applications, these devices are perfectly matched to operate with MOSFETs or high speed IGBTs.

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Repetitive peak reverse voltage	V _{RRM}		1200	V		
Average rectified forward current	I _{F(AV)}	T _C = 105 °C, D = 0.50	30			
Non-repetitive peak surge current	I _{FSM}	T_{C} = 45 °C, t_{p} = 10 ms, sine wave	210	А		
Repetitive peak forward current	I _{FRM}	T _C = 105 °C, D = 0.50, f = 20 kHz	60			
Operating junction and storage temperature	T _J , T _{Stg}		-55 to +175	°C		

ELECTRICAL SPECIFICATIONS (T _J = 25 $^{\circ}$ C unless otherwise specified)								
PARAMETER	SYMBOL	MBOL TEST CONDITIONS MIN. TYP. MAX. U						
Breakdown voltage, blocking voltage	V_{BR}, V_{R}	I _R = 100 μA	1200	-	-			
Forward voltage	V _F	I _F = 30 A	-	2.6	3.15	V		
		I _F = 30 A, T _J = 125 °C	-	2.1	-			
Deverse la clue de comment	I _R	$V_{\rm R} = V_{\rm R}$ rated	-	-	50	μA		
Reverse leakage current		$T_J = 125 \text{ °C}, V_R = V_R \text{ rated}$	-	-	500			
Junction capacitance	C _T V _R = 200 V		-	17	-	pF		
Series inductance	Ls	Measured to lead 5 mm from package body	-	8	-	nH		

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DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CO	MIN.	TYP.	MAX.	UNITS	
		$I_F = 1.0 \text{ A}, \text{ d}I_F/\text{d}t = 100$	I _F = 1.0 A, dI _F /dt = 100 A/µs, V _R = 30 V		26	-	
Reverse recovery time	t _{rr}	T _J = 25 °C		-	100	-	ns
		T _J = 125 °C		-	150	-	
Peak recovery current	I	T _J = 25 °C	I _F = 20 A dI _F /dt = 600 A/µs V _R = 400 V	-	12	-	A
Feak recovery current	I _{RRM}	T _J = 125 °C		-	22	-	
Reverse recovery charge	Q _{rr}	T _J = 25 °C		-	530	-	nC
neverse recovery charge	Qrr	T _J = 125 °C		-	1550	-	
Powerse recovery time	+	T _J = 25 °C		-	80	-	ns
Reverse recovery time	t _{rr}	T _J = 125 °C		-	120	-	
Deals receiver a current		T _J = 25 °C	I _F = 30 A dI _F /dt = 1000 A/μs V _R = 800 V	-	22	-	A
Peak recovery current	IRRM	T _J = 125 °C		-	37	-	
	0	T _J = 25 °C		-	900	-	nC
Reverse recovery charge	Q _{rr}	T _J = 125 °C	1	-	2300	-	

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Thermal resistance, junction-to-case	R _{thJC}		-	-	0.8	°C/W	
			-	5.5	-	g	
Weight			-	0.2	-	oz.	
Mounting torque			6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)	
Maximum junction and storage temperature range	T _J , T _{Stg}		-55	-	175	°C	
Marking device		Case style: TO-247AD 2L		E5PX	3012L		



Fig. 1 - Typical Forward Voltage Drop Characteristics



Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

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Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

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Fig. 5 - Thermal Impedance Z_{thJC} - Characteristics



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Fig. 8 - Typical Recovery Current vs. dl_F/dt



Fig. 9 - Reverse Recovery Waveform and Definitions

Notes

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- $^{(1)}$ di_F/dt rate of change of current through zero crossing
- ⁽²⁾ I_{RRM} peak reverse recovery current
- ⁽³⁾ t_{rr} reverse recovery time measured from t_0 , crossing point of negative going I_F, to point $t_{10\%}$, 0.1 I_{RRM}
- $^{(4)}~Q_{rr}$ area under curve defined by t_0 and $t_{10~\%}$

$$Q_{rr} = \int_{t_0}^{t_{10\%}} I(t) dt$$

 $^{(5)}$ di_(rec)M/dt - peak rate of change of current during t_b portion of t_{rr}

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ORDERING INFORMATION TABLE



ORDERING INFORMATION (Example)						
PREFERRED P/N	QUANTITY PER TUBE	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION			
VS-E5PX3012L-N3	25	500	Antistatic plastic tube			

LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?95536			
Part marking information www.vishay.com/doc?95648				
Spice model	www.vishay.com/doc?96684			

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Outline Dimensions

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TO-247AD 2L

DIMENSIONS in millimeters and inches







<u>View B</u>

SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STMDUL	MIN.	MAX.	MIN.	MAX.	NUTES
Α	4.65	5.31	0.183	0.209	
A1	2.21	2.59	0.087	0.102	
A2	1.50	2.49	0.059	0.098	
b	0.99	1.40	0.039	0.055	
b1	0.99	1.35	0.039	0.053	
b2	1.65	2.39	0.065	0.094	
b3	1.65	2.34	0.065	0.092	
с	0.38	0.89	0.015	0.035	
c1	0.38	0.84	0.015	0.033	
D	19.71	20.70	0.776	0.815	3
D1	13.08	-	0.515	-	4
D2	0.51	1.35	0.020	0.053	

MIN.	MAX.	MIN.		NOTES
15.00		IVIIIN.	MAX.	
15.29	15.87	0.602	0.625	3
13.46	-	0.53	-	
5.46	BSC	0.215	BSC	
0.2	54	0.0)10	
19.81	20.32	0.780	0.800	
3.71	4.29	0.146	0.169	
3.56	3.66	0.14	0.144	
-	6.98	-	0.275	
5.31	5.69	0.209	0.224	
4.52	5.49	0.178	0.216	
5.51	BSC	0.217	BSC	
	5.46 0.2 19.81 3.71 3.56 - 5.31 4.52	5.46 BSC 0.254 19.81 20.32 3.71 4.29 3.56 3.66 - 6.98 5.31 5.69	5.46 BSC 0.215 0.254 0.0 19.81 20.32 0.780 3.71 4.29 0.146 3.56 3.66 0.14 - 6.98 - 5.31 5.69 0.209 4.52 5.49 0.178	5.46 BSC 0.215 BSC 0.254 0.010 19.81 20.32 0.780 0.800 3.71 4.29 0.146 0.169 3.56 3.66 0.14 0.144 - 6.98 - 0.275 5.31 5.69 0.209 0.224 4.52 5.49 0.178 0.216

Notes

⁽¹⁾ Dimensioning and tolerancing per ASME Y14.5M-1994

(2) Contour of slot optional

⁽³⁾ Dimension D and E do not include mold flash. These dimensions are measured at the outermost extremes of the plastic body

⁽⁴⁾ Thermal pad contour optional with dimensions D1 and E1

⁽⁵⁾ Lead finish uncontrolled in L1

(6) Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")

⁽⁷⁾ Outline conforms to JEDEC[®] outline TO-247 with exception of dimension A min., D, E min., Q min., S, and note 4

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